

ASM3P2855B

rev 0.3

Custom Clock Generator for Fax System

Features

- Generates Custom Clocks for FAX system from an inexpensive 24MHz Crystal
- 7 x 50MHz synchronized non-Spread Spectrum clocks (for CPU, ASIC2, ASIC3, HDD, and PCI Analyzer, Ethernet, and LAN PHY)
- 1 x 50MHz for CPU Timer

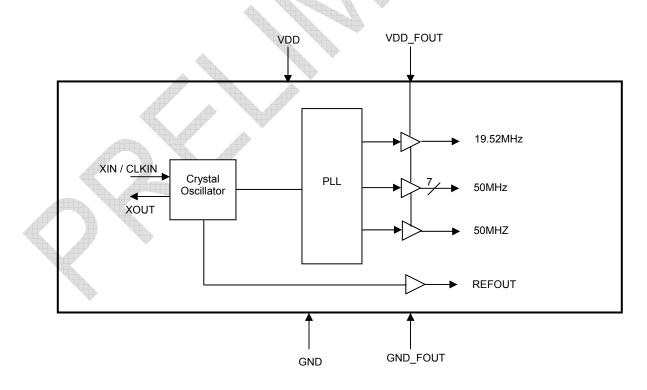
Product Description

ASM3P2855B is a part of the two chip custom clock generator solution for NEC FAX system. Together with ASM3P2854A, ASM3P2855B realizes all the eighteen clocks required by the various components and subsystems of the FAX system. It uses an inexpensive 24MHz crystal as the input to generate five synchronized 50MHz non-spread PCI clocks used by CPU, HDD, PCI Analyzer, ASIC2 and ASIC3, two non-spread

- 1x 19.52MHz non-spread clock for Scanner
- REFOUT Clock
- Supply Voltage 3.3 V +/- 0.3V
- Available in 16L TSSOP, Green package
- Commercial Temperature operation

synchronized 50MHz clocks for Ethernet and LAN PHY, a 50MHz clock for the CPU Timer, and a 19.52MHz nonspread clock used by ASIC1 for Scanner. The custom clock generator ASM3P2855B works with a Supply Voltage of 3.3V. The device is available in a 16L TSSOP Green package and in commercial temperature range.

Block Diagram



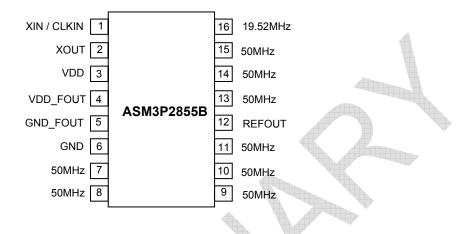
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Pin Diagram



Pin Description

Pin#	Pin Name	Туре	Description
1	XIN / CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.
3	VDD	Р	Power supply for the core
4	VDD_FOUT	Р	Power supply for the output buffers.
5	GND_FOUT	Р	Ground connection for the output buffers
6	GND	Р	Ground connection
7	50MHz	0	Synchronous 50MHz Clock Output
8	50MHz	0	Synchronous 50MHz Clock Output
9	50MHz	0	Synchronous 50MHz Clock Output
10	50MHz	0	Synchronous 50MHz Clock Output
11	50MHz	0	Synchronous 50MHz Clock Output
12	REFOUT	o	24MHz Reference Clock Out put
13	50MHz	0	Synchronous 50MHz Clock Output
14	50MHz	0	Synchronous 50MHz Clock Output
15	50MHz	0	50MHz Clock Output
16	19.52MHz	0	19.52MHz Clock Output



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Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
VDD, VDD_FOUT	Power Supply Voltage relative to GND	-0.5 to +4.6	V
V _{IN}	Input Voltage relative to GND (Input Pins)	-0.5 to VDD+0.5	
T _{STG}	Storage temperature	-65 to +125	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T _{DV}	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV

device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Units
T _A	Operating Temperature	0		+70	°C
VDD	Core Voltage	+3.0	+3.3	+3.6	V
VDD_FOUT	Output Voltage	+3.0	+3.3	+3.6	V

DC Electrical Characteristics

Symbol	Parameter	Min	Тур	Max	Unit	
V _{IL}	Input low voltage	GND - 0.3		0.8	V	
VIH	Input high voltage	2.0		VDD + 0.3	V	
IIL	Input low current			-35	μA	
IIH	Input high current			35	μA	
I _{XOL}	XOUT output low current (V _{XOL} @0.4V, VDD=3.3V)		3		mA	
I _{XOH}	XOUT output high current (V _{XOH} @2.5V, VDD=3.3V)		3		mA	
Vol	Output low voltage (VDD = 3.3V, I _{OL} = 10mA)			0.4	V	
V _{OH}	Output high voltage (VDD = 3.3V, I _{OH} = 10mA)	2.5			V	
IDD	Static supply current*		10		mA	
Icc	Dynamic supply current (VDD =3.3V)		28		mA	
VDD	Operating Voltage	3.0	3.3	3.6	V	
VDD_FOUT	Operating Voltage	3.0	3.3	3.6	V	
t _{on}	Power-up time (first locked cycle after power-up)			5	mS	
Z _{OUT}	Output impedance		29		Ω	
* XIN is pulled low						



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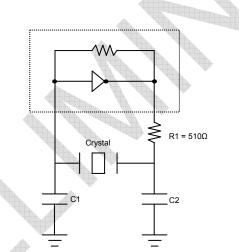
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AC Electrical Characteristics

Symbol	P	Min	Тур	Max	Unit	
XIN / CLKIN	Input frequency		24	4	MHz	
		At Pins 7,8,9,10,11,13,14,15		50		
Fout	Output frequency	At Pin 12		24		MHz
		At Pin 16		19.52		
t _{LH} *	Output rise time (measu	Output rise time (measured from 0.8 to 2.0V)			A	nS
t _{HL} *	t _{HL} * Output fall time (measured at 2.0V to 0.8V) t _{JC} Jitter (Cycle to cycle)			0.7		nS
t _{JC}				250		pS
t _D	Output duty cycle	40	50	60	%	
* t _{LH} and t _{HL} are measured into a capacitive load of 15pF						

Typical Crystal Oscillator Circuit



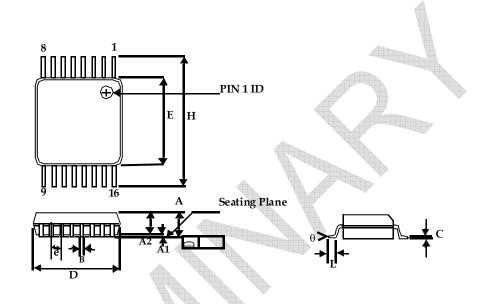
Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal			
Nominal frequency	24MHz		
Frequency tolerance	± 50 ppm or better at 25°C		
Operating temperature range	-25°C to +85°C		
Storage temperature	-40°C to +85°C		
Load capacitance	18pF		
Shunt capacitance	7pF maximum		
ESR	25 Ω		



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Package Information



16-lead Thin Shrunk Small Outline	Package (4.40-MM Body)
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		Dimensions				
	Symbol	Inches		Millimeters		
	Symbol	Min	Max	Min	Max	
	A		0.043		1.20	
	A1	0.002	0.006	0.05	0.15	
	A2	0.031	0.041	0.80	1.05	
A0000	В	0.007	0.012	0.19	0.30	
	С	0.004	0.008	0.09	0.20	
	D	0.193	0.201	4.90	5.10	
	E	0.169	0.177	4.30	4.50	
	е	0.026	BSC	0.65 BSC		
	Н	0.252	BSC	6.40	BSC	
	L	0.020	0.030	0.50	0.75	
	θ	0°	8°	0°	8°	

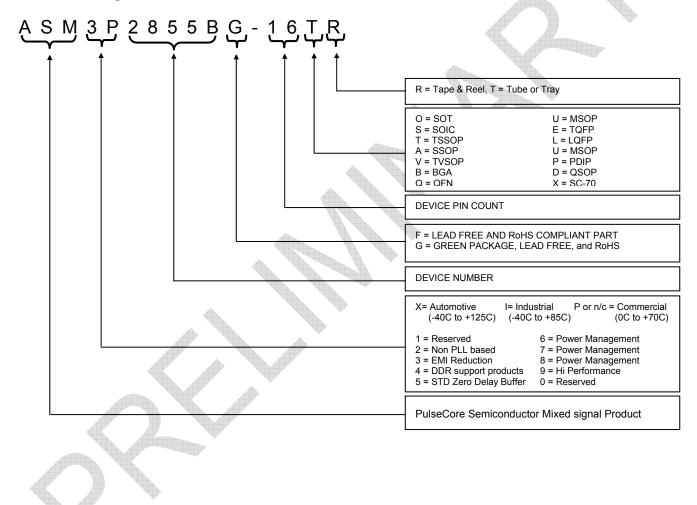


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Ordering Codes

Ordering Code	Marking	Package Type	Operating Range
ASM3P2855BG-16TT	3P2855BG	16-pin 4.4-mm TSSOP - TUBE, Green	Commercial
ASM3P2855BG-16TR	3P2855BG	16-pin 4.4-mm TSSOP - TAPE & REEL, Green	Commercial

Device Ordering Information



Licensed under U.S Patent Nos 5,488,627 and 5,631,921



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Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003

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